CNA1301H

Photo Interrupter

For contactless SW, object detection

Overview

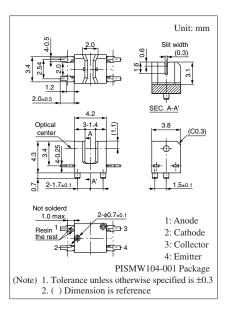
CNA1301H is an ultraminiature, highly reliable transmissive photosensor in which a high efficiency GaAs infrared light emitting diode chip and a high sensitivity Si phototransistor chip are integrated in a double molded resin package.

■ Features

- Ultraminiature: 3.8 mm × 4.2 mm (height: 4.3 mm)
- Highly precise position detection: 0.15 mm
- Gap width: 1.4 mm
- Support for thin equipment (permits direct mounting on printed circuit board)

■ Absolute Maximum Ratings $T_a = 25$ °C

	Symbol	Rating	Unit	
Input (Light	Reverse voltage	V_R	6	V
emitting diode)	Forward current	I_F	50	mA
	Power dissipation *1	P_{D}	75	mW
Output (Photo	Collector-emitter voltage	V_{CEO}	35	V
transistor)	(Base open)			
	Emitter-collector voltage	V_{ECO}	6	V
	(Base open)			
	Collector current	I_C	20	mA
	Collector power dissipation *2	P _C	75	mW
Temperature	Operating ambient temperature	Topr	-25 to +85	°C
	Storage temperature	T _{stg}	-40 to +100	°C



Note) *1: Input power derating ratio is 1.0 mW/°C at $T_a \ge 25$ °C.

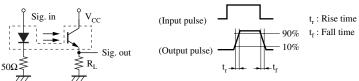
*2: Output power derating ratio is 1.33 mW/°C at $T_a \ge 25$ °C.

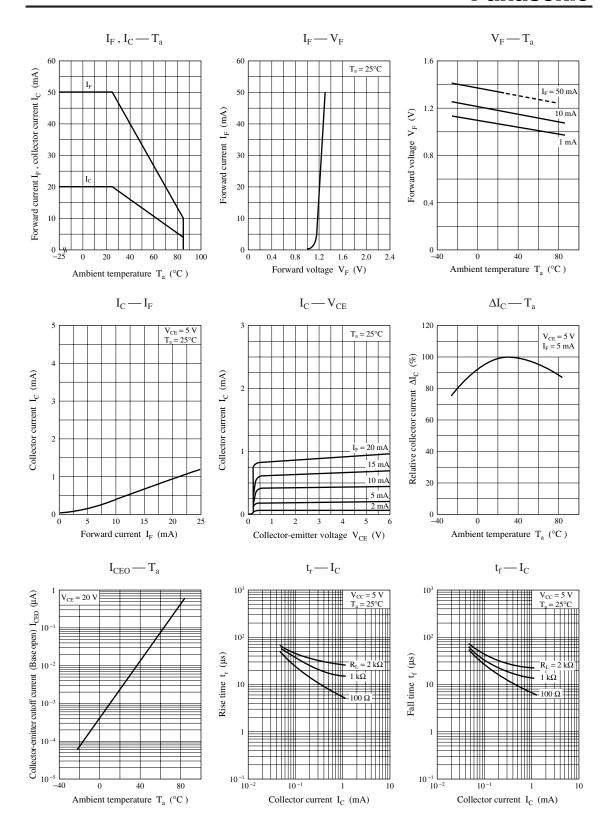
■ Electrical-Optical Characteristics $T_a = 25$ °C ± 3 °C

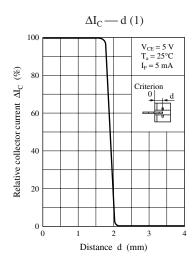
	Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input	Forward voltage	V_F	$I_F = 20 \text{ mA}$		1.2	1.4	V
characteristics	Reverse current	I_R	$V_R = 3 V$			10	μΑ
Output	Collector-emitter cutoff current	I_{CEO}	$V_{CE} = 20 \text{ V}$			100	nA
characteristics	(Base open)						
Transfer	Collector current	I_{C}	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	100		1300	μΑ
characteristics	Collector-emitter saturation voltage	V _{CE(sat)}	$I_F = 10 \text{ mA}, I_C = 50 \mu\text{A}$			0.4	V
	Rise time *	t _r	$V_{CC} = 5 \text{ V}, I_{C} = 0.1 \text{ mA}$		35		μs
	Fall time *	$t_{\rm f}$	$R_L = 1000~\Omega$		35		μs

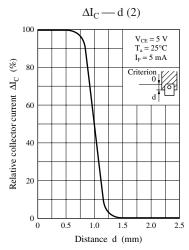
Note) 1. Input and output are practiced by electricity.

- 2. This device is designed be disregarded radiation.
- 3. *: Switching time measurement circuit









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Caution for Safety

⚠ DANGER

■ This product contains Gallium Arsenide (GaAs).

GaAs powder and vapor are hazardous to human health if inhaled or ingested. Do not burn, destroy, cut, cleave off, or chemically dissolve the product. Follow related laws and ordinances for disposal. The product should be excluded form general industrial waste or household garbage.

Request for your special attention and precautions in using the technical information and semiconductors described in this material

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- Any applications other than the standard applications intended.
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